NSN 5961-00-485-4976

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View Online at https://aerobasegroup.com/nsn/5961-00-485-4976 **Inclosure Material:** Metal **Overall Length:** 0.535 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.855 inches and 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage, dc and 10.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 10.00 amperes source cutoff current and 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No